





**TXS0104E** SCES651K - JUNE 2006 - REVISED OCTOBER 2023

# TXS0104E 4-Bit Bidirectional Voltage-Level Translator for **Open-Drain and Push-Pull Applications**

#### 1 Features

- No direction-control signal needed
- Maximum data rates:
  - 24Mbps (push pull)
  - 2Mbps (open drain)
- Available in the Texas Instruments NanoFree™ package
- 1.65 V to 3.6 V on A port and 2.3 V to 5.5 V on B port  $(V_{CCA} \le V_{CCB})$
- No power-supply sequencing required V<sub>CCA</sub> or V<sub>CCB</sub> can be ramped first
- Latch-up performance exceeds 100 mA per JESD 78, class II
- ESD protection exceeds JESD 22:
  - A port:
    - 2000-V Human-Body Model (A114-B)
    - 200-V Machine Model (A115-A)
    - 1000-V Charged-Device Model (C101)
  - B port:
    - 15-kV Human-Body Model (A114-B)
    - 200-V Machine Model (A115-A)
    - 1000-V Charged-Device Model (C101)
- IEC 61000-4-2 ESD (B port):
  - ±8-kV contact discharge
  - ±10-kV air-gap discharge

### 2 Applications

- Handset
- **Smartphone**
- **Tablet**
- **Desktop PC**

## 3 Description

This 4-bit non-inverting translator uses two separate configurable power-supply rails. The A port is designed to track  $V_{CCA}.\ V_{CCA}$  accepts any supply voltage from 1.65 V to 3.6 V.  $V_{CCA}$  must be less than or equal to V<sub>CCB</sub>. The B port is designed to track V<sub>CCB</sub>. V<sub>CCB</sub> accepts any supply voltage from 2.3 V to 5.5 V. This allows for low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state.

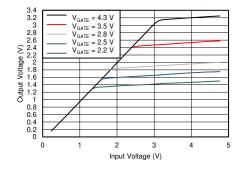
The TXS0104E is designed so that the OE input circuit is supplied by V<sub>CCA</sub>.

For the high-impedance state during power up or power down, tie OE to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

#### **Package Information**

| . dowagoo              |  |  |  |  |  |  |  |
|------------------------|--|--|--|--|--|--|--|
| PACKAGE <sup>(1)</sup> | PACKAGE SIZE <sup>(2)</sup>  |  |  |  |  |  |  |
| D (SOIC, 14)           | 8.65 mm × 6 mm   |  |  |  |  |  |  |
| PW (TSSOP, 14)         | 5 mm × 6.4 mm  |  |  |  |  |  |  |
| ZXU (BGA, 12)          | 2 mm × 2.5 mm  |  |  |  |  |  |  |
| RGY (VQFN, 14)         | 3.5 mm × 3.5 mm  |  |  |  |  |  |  |
| YZT (DSBGA, 12)        | 2.25 mm × 1.75 mm  |  |  |  |  |  |  |
| NMN (nFBGA, 12)        | 2 mm × 2.5 mm  |  |  |  |  |  |  |
| BQA (WQFN, 12)         | 3 mm × 2.5 mm  |  |  |  |  |  |  |
| RUT (UQFN, 12)         | 2.00 mm × 1.70 mm  |  |  |  |  |  |  |
|                        | PACKAGE <sup>(1)</sup> D (SOIC, 14) PW (TSSOP, 14) ZXU (BGA, 12) RGY (VQFN, 14) YZT (DSBGA, 12) NMN (nFBGA, 12) BQA (WQFN, 12) |  |  |  |  |  |  |

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable



Transfer Characteristics of an N-Channel Transistor



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Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout

Product Folder Links: TXS0104E

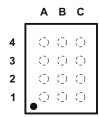
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| • | Deleted the ordering table   | 1    |
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|   | section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Inforr section  Deleted the Package thermal impedance information from the Absolute max ratings table into the There | 1    |



## **5 Pin Configuration and Functions**



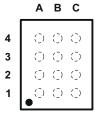


Figure 5-1. ZXU Package, 12-Pin MICROSTAR JUNIOR (Top View)

Figure 5-2. NMN Package, 12-Pin nFBGA (Top View)

Table 5-1. Pin Functions: ZXU/ NMN

| PIN |                  | TYPE <sup>(1)</sup> | DESCRIPTION   |  |
|-----|------------------|---------------------|---|--|
| NO. | NAME             | ITPE                | DESCRIPTION   |  |
| A1  | A1               | I/O                 | Input/output A1. Referenced to V <sub>CCA</sub> .   |  |
| A2  | A2               | I/O                 | Input/output A2. Referenced to V <sub>CCA</sub> .   |  |
| A3  | A3               | I/O                 | Input/output A3. Referenced to V <sub>CCA</sub> .   |  |
| A4  | A4               | I/O                 | Input/output A4. Referenced to V <sub>CCA</sub> .   |  |
| C1  | B1               | I/O                 | Input/output B1. Referenced to V <sub>CCB</sub> .   |  |
| C2  | B2               | I/O                 | Input/output B2. Referenced to V <sub>CCB</sub> .   |  |
| C3  | В3               | I/O                 | Input/output B3. Referenced to V <sub>CCB</sub> .   |  |
| C4  | B4               | I/O                 | Input/output B4. Referenced to V <sub>CCB</sub> .   |  |
| B4  | GND              | _                   | Ground  |  |
| В3  | OE               | I                   | 3-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to $V_{\text{CCA}}$ .    |  |
| B2  | V <sub>CCA</sub> | _                   | A-port supply voltage. 1.65 V $\leq$ V <sub>CCA</sub> $\leq$ 3.6 V and V <sub>CCA</sub> $\leq$ V <sub>CCB</sub> . |  |
| B1  | V <sub>CCB</sub> | _                   | B-port supply voltage. 2.3 V ≤ V <sub>CCB</sub> ≤ 5.5 V.  |  |

(1) I = input, O = output



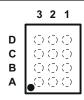


Figure 5-3. YZT Package, 12-Pin DSBGA (Top View)

Table 5-2. Pin Functions: DSBGA

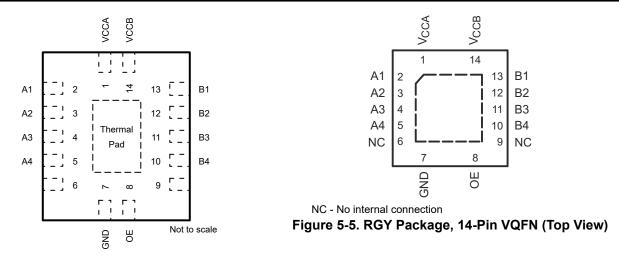
| F   | PIN              | TYPE <sup>(1)</sup> | DESCRIPTION   |
|-----|------------------|---------------------|---|
| NO. | NAME             | ITPE                | DESCRIPTION   |
| A3  | A1               | I/O                 | Input/output A1. Referenced to V <sub>CCA</sub> .   |
| В3  | A2               | I/O                 | Input/output A2. Referenced to V <sub>CCA</sub> .   |
| C3  | A3               | I/O                 | Input/output A3. Referenced to V <sub>CCA</sub> .   |
| D3  | A4               | I/O                 | Input/output A4. Referenced to V <sub>CCA</sub> .   |
| A1  | B1               | I/O                 | Input/output B1. Referenced to V <sub>CCB</sub> .   |
| B1  | B2               | I/O                 | Input/output B2. Referenced to V <sub>CCB</sub> .   |
| C1  | В3               | I/O                 | Input/output B3. Referenced to V <sub>CCB</sub> .   |
| D1  | B4               | I/O                 | Input/output B4. Referenced to V <sub>CCB</sub> .   |
| D2  | GND              | _                   | Ground  |
| C2  | OE               | I                   | 3-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to V <sub>CCA</sub> .    |
| B2  | V <sub>CCA</sub> | _                   | A-port supply voltage. 1.65 V $\leq$ V <sub>CCA</sub> $\leq$ 3.6 V and V <sub>CCA</sub> $\leq$ V <sub>CCB</sub> . |
| A2  | V <sub>CCB</sub> | _                   | B-port supply voltage. 2.3 V ≤ V <sub>CCB</sub> ≤ 5.5 V.  |

<sup>(1)</sup> I = input, O = output

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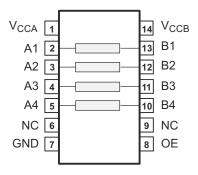
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NC - No internal connection

Figure 5-4. BQA Package, 14-Pin WQFN (Top View)



NC - No internal connection

Figure 5-6. D and PW Package, 14-Pin SOIC and TSSOP (Top View)

Table 5-3. Pin Functions: D, PW, or RGY

|                  | PIN | - <b>TYPE</b> (1) | DESCRIPTION   |  |
|------------------|-----|-------------------|---|--|
| NAME             | NO. | ITPE              | DESCRIPTION   |  |
| A1               | 2   | I/O               | Input/output A1. Referenced to V <sub>CCA</sub> .   |  |
| A2               | 3   | I/O               | Input/output A2. Referenced to V <sub>CCA</sub> .   |  |
| A3               | 4   | I/O               | Input/output A3. Referenced to V <sub>CCA</sub> .   |  |
| A4               | 5   | I/O               | Input/output A4. Referenced to V <sub>CCA</sub> .   |  |
| B1               | 13  | I/O               | Input/output B1. Referenced to V <sub>CCB</sub> .   |  |
| B2               | 12  | I/O               | Input/output B2. Referenced to V <sub>CCB</sub> .   |  |
| B3               | 11  | I/O               | Input/output B3. Referenced to V <sub>CCB</sub> .   |  |
| B4               | 10  | I/O               | Input/output B4. Referenced to V <sub>CCB</sub> .   |  |
| GND              | 7   | _                 | Ground  |  |
| OE               | 8   | I                 | 3-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to $V_{\text{CCA}}$ .    |  |
| V <sub>CCA</sub> | 1   | _                 | A-port supply voltage. 1.65 V $\leq$ V <sub>CCA</sub> $\leq$ 3.6 V and V <sub>CCA</sub> $\leq$ V <sub>CCB</sub> . |  |
| V <sub>CCB</sub> | 14  | _                 | B-port supply voltage. 2.3 V ≤ V <sub>CCB</sub> ≤ 5.5 V.  |  |
| Thermal Pa       | ad  | _                 | For the RGY package, the exposed center thermal pad must be connected to ground                                   |  |



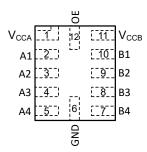


Figure 5-7. RUT Package, 12-Pin UQFN (Transparent Top View)

Table 5-4. Pin Functions: RUT

| P                | IN  | TYPE <sup>(1)</sup> | DESCRIPTION   |  |
|------------------|-----|---------------------|---|--|
| NAME             | NO. | I I I PE('')        | DESCRIPTION   |  |
| A1               | 2   | I/O                 | Input/output A1. Referenced to V <sub>CCA</sub> .   |  |
| A2               | 3   | I/O                 | Input/output A2. Referenced to V <sub>CCA</sub> .   |  |
| A3               | 4   | I/O                 | Input/output A3. Referenced to V <sub>CCA</sub> .   |  |
| A4               | 5   | I/O                 | Input/output A4. Referenced to V <sub>CCA</sub> .   |  |
| B1               | 10  | I/O                 | Input/output B1. Referenced to V <sub>CCB</sub> .   |  |
| B2               | 9   | I/O                 | Input/output B2. Referenced to V <sub>CCB</sub> .   |  |
| В3               | 8   | I/O                 | Input/output B3. Referenced to V <sub>CCB</sub> .   |  |
| B4               | 7   | I/O                 | Input/output B4. Referenced to V <sub>CCB</sub> .   |  |
| GND              | 6   | _                   | Ground  |  |
| OE               | 12  | I                   | 3-state output-mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to V <sub>CCA</sub> .    |  |
| V <sub>CCA</sub> | 1   | _                   | A-port supply voltage. 1.65 V $\leq$ V <sub>CCA</sub> $\leq$ 3.6 V and V <sub>CCA</sub> $\leq$ V <sub>CCB</sub> . |  |
| V <sub>CCB</sub> | 11  | _                   | A-port supply voltage. 1.65 V $\leq$ V <sub>CCA</sub> $\leq$ 3.6 V and V <sub>CCA</sub> $\leq$ V <sub>CCB</sub> . |  |

<sup>(1)</sup> I = input, O = output

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Product Folder Links: TXS0104E



## **6 Specifications**

## **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

|   |                    | MIN  | MAX                    | UNIT |
|---|--------------------|------|------------------------|------|
| Supply voltage, V <sub>CCA</sub>  |                    | -0.5 | 4.6                    | V    |
| Supply voltage, V <sub>CCB</sub>  |                    | -0.5 | 6.5                    | V    |
| Input voltage, V <sub>I</sub> <sup>(2)</sup>  | A port             | -0.5 | 4.6                    | V    |
| Imput voltage, v  | B port             | -0.5 | 6.5                    | V    |
| Voltage range applied to any output in the high-impedance or power-off state, $V_0^{(2)}$ | A port             | -0.5 | 4.6                    | V    |
| orage range applied to any output in the high-impedance of power-on state, vo vi          | B port             | -0.5 | 6.5                    | V    |
| /oltage range applied to any output in the high or low state, $V_{O}^{\ (2)\ (3)}$        | A port             | -0.5 | V <sub>CCA</sub> + 0.5 | V    |
|   | B port             | -0.5 | V <sub>CCB</sub> + 0.5 | V    |
| Input clamp current, I <sub>IK</sub>  | V <sub>I</sub> < 0 |      | -50                    | mA   |
| Output clamp current, I <sub>OK</sub>   | V <sub>O</sub> < 0 |      | -50                    | mA   |
| Continuous output current, I <sub>O</sub>   |                    | -50  | 50                     | mA   |
| Continuous current through each V <sub>CCA</sub> , V <sub>CCB</sub> , or GND              |                    |      | 100                    | mA   |
| perating junction temperature, T <sub>J</sub>   |                    |      | 150                    | °C   |
| Storage temperature, T <sub>STG</sub>   |                    | -65  | 150                    | °C   |

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V<sub>CCA</sub> and V<sub>CCB</sub> are provided in the recommended operating conditions table.

## 6.2 ESD Ratings

|  |                                      |  |        | VALUE | UNIT |
|--|--------------------------------------|--|--------|-------|------|
| V <sub>(ESD)</sub> Electrostatic discharge |                                      | Human body model (HBM), per ANSI/ESDA/JEDEC  | A Port | ±2000 | V    |
|  | JS-001, all pins <sup>(1)</sup>      | B Port   | ±15    | kV    |      |
|  | Electrostatic discharge              | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup> | A Port | ±1000 | V    |
|  | JESD22-C101, all pins <sup>(2)</sup> | B Port   | ±1000  | V     |      |
|  | Machine model (MM)                   | A Port   | ±200   | V     |      |
|  |                                      | B Port   | ±200   | V     |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



## **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup> (2)

|                 |                                    |                                     | V <sub>CCA</sub> | V <sub>CCB</sub> | MIN                     | MAX                     | UNIT |
|-----------------|------------------------------------|-------------------------------------|------------------|------------------|-------------------------|-------------------------|------|
| $V_{CCA}$       | Supply voltage <sup>(3)</sup>      |                                     |                  |                  | 1.65                    | 3.6                     | V    |
| $V_{CCB}$       | Supply voltage <sup>(3)</sup>      |                                     |                  |                  | 2.3                     | 5.5                     | V    |
|                 |                                    | A nort I/Os                         | 1.65 V to 1.95 V | 2.3 V to 5.5 V   | V <sub>CCI</sub> - 0.2  | V <sub>CCI</sub>        |      |
| .,              | High lavel innet callana           | A-port I/Os                         | 2.3 V to 3.6 V   | 2.3 V to 5.5 V   | V <sub>CCI</sub> - 0.4  | V <sub>CCI</sub>        | V    |
| $V_{IH}$        | High-level input voltage           | B-port I/Os                         | 1.65 V to 3.6 V  | 2.3 V to 5.5 V   | V <sub>CCI</sub> - 0.4  | V <sub>CCI</sub>        | V    |
|                 |                                    | OE input                            | 1.65 V to 3.6 V  | 2.3 V to 5.5 V   | V <sub>CCA</sub> × 0.65 | 5.5                     |      |
| V <sub>IL</sub> | Low-level input voltage            | A-port I/Os                         | 1.65 V to 3.6 V  | 2.3 V to 5.5 V   | 0                       | 0.15                    |      |
|                 |                                    | B-port I/Os                         | 1.65 V to 3.6 V  | 2.3 V to 5.5 V   | 0                       | 0.15                    | V    |
|                 |                                    | OE input                            | 1.65 V to 3.6 V  | 2.3 V to 5.5 V   | 0                       | V <sub>CCA</sub> × 0.35 |      |
|                 |                                    | A-port I/Os<br>push-pull<br>driving | 1.65 V to 3.6 V  | 2.3 V to 5.5 V   |                         | 10                      |      |
| Δt/Δν           | Input transition rise or fall rate | B-port I/Os<br>push-pull<br>driving | 1.65 V to 3.6 V  | 2.3 V to 5.5 V   |                         | 10                      | ns/V |
|                 |                                    | Control input                       | 1.65 V to 3.6 V  | 2.3 V to 5.5 V   |                         | 10                      |      |
| T <sub>A</sub>  | Operating free-air temperature     |                                     |                  |                  | -40                     | 85                      | °C   |

 $<sup>\</sup>ensuremath{V_{\text{CCI}}}$  is the supply voltage associated with the input port.

## 6.4 Thermal Information: ZXU, YZT, and NMN

|                               |  | TX  |                |                |      |
|-------------------------------|--|---|----------------|----------------|------|
| THERMAL METRIC <sup>(1)</sup> |  | ZXU<br>(BGA MICROSTAR<br>JUNIOR) <sup>(2)</sup> | YZT<br>(DSBGA) | NMN<br>(NFGBA) | UNIT |
|                               |  | 12 PINS   | 12 PINS        | 12 PINS        |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 132.0   | 89.2           | 134.3          | °C/W |
| R <sub>0JC(top)</sub>         | Junction-to-case (top) thermal resistance    | 98.4  | 0.9            | 90.7           | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 68.7  | 14.4           | 88.4           | °C/W |
| ΨЈТ                           | Junction-to-top characterization parameter   | 3.1   | 3.0            | 4.3            | °C/W |
| ΨЈВ                           | Junction-to-board characterization parameter | 68.2  | 14.4           | 89.3           | °C/W |

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

 $V_{CCO}$  is the supply voltage associated with the output port.  $V_{CCA}$  must be less than or equal to  $V_{CCB}$ , and  $V_{CCA}$  must not exceed 3.6 V.



## 6.5 Thermal Information: D, PW, and RGY

|                       |  | TXS0104E |                            |                              |                              |      |
|-----------------------|--|----------|----------------------------|------------------------------|------------------------------|------|
|                       | THERMAL METRIC(1)                            |          | D<br>(SOIC) <sup>(1)</sup> | PW<br>(TSSOP) <sup>(2)</sup> | RGY<br>(VQFN) <sup>(3)</sup> | UNIT |
|                       |  |          | 14 PINS                    | 14 PINS                      | 14 PINS                      |      |
| $R_{\theta JA}$       | Junction-to-ambient thermal resistance       |          | 90.4                       | 120.1                        | 56.1                         | °C/W |
| R <sub>0JC(top)</sub> | Junction-to-case (top) thermal resistance    |          | 50.1                       | 49.4                         | 68.8                         | °C/W |
| $R_{\theta JB}$       | Junction-to-board thermal resistance         |          | 45.0                       | 61.8                         | 32.1                         | °C/W |
| ΨЈТ                   | Junction-to-top characterization parameter   |          | 14.4                       | 6.2                          | 3.1                          | °C/W |
| ΨЈВ                   | Junction-to-board characterization parameter |          | 44.7                       | 61.2                         | 32.3                         | °C/W |
| R <sub>0JC(bot)</sub> | Junction-to-case (bottom) thermal resistance |          | _                          | _                            | 12.8                         | °C/W |

- For more information about traditional and new thermal metrics, see the <u>Semiconductor and IC Package Thermal Metrics</u> application report.
- (2) The package thermal impedance is calculated in accordance with JESD 51-7.
- (3) The package thermal impedance is calculated in accordance with JESD 51-5.

#### 6.6 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (1) (2) (3)

|                                     | PARAMETER                       | TEST CONDITIONS   | V <sub>CCA</sub>           | V <sub>CCB</sub> | MIN                    | TYP MAX | UNIT |
|-------------------------------------|---------------------------------|---|----------------------------|------------------|------------------------|---------|------|
| V <sub>OHA</sub>                    | Port A output<br>high voltage   | $I_{OH} = -20 \mu A,$<br>$V_{IB} \ge V_{CCB} - 0.4 V$<br>$T_A = -40^{\circ}C \text{ to } 85^{\circ}C$         | 1.65 V to 3.6 V            | 2.3 V to 5.5 V   | V <sub>CCA</sub> × 0.8 |         | V    |
| V <sub>OLA</sub>                    | Port A output<br>low voltage    | $I_{OL} = 1 \text{ mA},$<br>$V_{IB} \le 0.15 \text{ V}$<br>$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$ | 1.65 V to 3.6 V            | 2.3 V to 5.5 V   |                        | 0.4     | V    |
| V <sub>OHB</sub>                    | Port B output<br>high voltage   | $I_{OH} = -20 \mu A,$<br>$V_{IA} \ge V_{CCA} - 0.2 V$<br>$T_A = -40^{\circ}C \text{ to } 85^{\circ}C$         | 1.65 V to 3.6 V            | 2.3 V to 5.5 V   | V <sub>CCB</sub> × 0.8 |         | V    |
| V <sub>OLB</sub>                    | Port B output<br>low voltage    | $I_{OL} = 1 \text{ mA},$<br>$V_{IA} \le 0.15 \text{ V}$<br>$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$ | 1.65 V to 3.6 V            | 2.3 V to 5.5 V   |                        | 0.4     | V    |
| I <sub>I</sub>                      | Input leakage                   | OE:<br>V <sub>I</sub> = V <sub>CCI</sub> or GND<br>T <sub>A</sub> = 25°C                                      | 1.65 V to 3.6 V            | 2.3 V to 5.5 V   | -1                     | 1       | μA   |
| ' current                           |                                 | V <sub>I</sub> = V <sub>CCI</sub> or GND<br>T <sub>A</sub> = -40°C to 85°C                                    | 1.65 V to 3.6 V            | 2.3 V to 5.5 V   | -2                     | 2       |      |
|                                     | High-impedance state            | A or B port:<br>OE = V <sub>IL</sub><br>T <sub>A</sub> = 25°C   | 1.65 V to 3.6 V            | 2.3 V to 5.5 V   | -1                     | 1       |      |
| l <sub>OZ</sub>                     | output current                  | A or B port:<br>OE = V <sub>IL</sub><br>T <sub>A</sub> = -40°C to 85°C  | 1.65 V to 3.6 V            | 2.3 V to 5.5 V   | -2                     | 2       | μA   |
|                                     |                                 | V <sub>I</sub> = V <sub>O</sub> = Open,   | 1.65 V to V <sub>CCB</sub> | 2.3 V to 5.5 V   |                        | 2.4     |      |
| I <sub>CCA</sub>                    | V <sub>CCA</sub> supply current | $I_{O} = 0$   | 3.6 V                      | 0                |                        | 2.2     | μA   |
|                                     |                                 | $T_A = -40$ °C to 85°C  | 0                          | 5.5 V            |                        | -1      |      |
|                                     |                                 | $V_1 = V_0 = Open,$   | 1.65 V to V <sub>CCB</sub> | 2.3 V to 5.5 V   |                        | 12      |      |
| I <sub>CCB</sub>                    | V <sub>CCB</sub> supply current | I <sub>O</sub> = 0  | 3.6 V                      | 0                |                        | -1      | μA   |
|                                     |                                 | $T_A = -40$ °C to 85°C  | 0                          | 5.5 V            |                        | 1       |      |
| I <sub>CCA</sub> + I <sub>CCB</sub> | Combined supply current         | $V_I = V_O = Open,$<br>$I_O = 0$<br>$T_A = -40^{\circ}C$ to 85°C  | 1.65 V to V <sub>CCB</sub> | 2.3 V to 5.5 V   |                        | 14.4    | μА   |
| C.                                  | Input capacitance               | OE:<br>T <sub>A</sub> = 25°C  | 3.3 V                      | 3.3 V            |                        | 2.5     | pF   |
| Cı                                  | при сараспапсе                  | OE:<br>T <sub>A</sub> = -40°C to 85°C   | 3.3 V                      | 3.3 V            |                        | 3.5     | pr   |



### 6.6 Electrical Characteristics (continued)

over recommended operating free-air temperature range (unless otherwise noted) (1) (2) (3)

|      | PARAMETER            | TEST CONDITIONS        | V <sub>CCA</sub> | V <sub>CCB</sub> | MIN TYP MAX | UNIT |
|------|----------------------|------------------------|------------------|------------------|-------------|------|
| 105. |                      | A port:                | 3.3 V            | 3.3 V            | 5           |      |
|      | Input-to-output      | T <sub>A</sub> = 25°C  | 3.3 V            | 3.3 V            | 6.5         | pF   |
|      | internal capacitance | B port:                | 3.3 V            | 3.3 V            | 12          | pr   |
|      |                      | $T_A = -40$ °C to 85°C | 3.3 V            | 3.3 V            | 16.5        |      |

- V<sub>CCI</sub> is the supply voltage associated with the input port.
- $V_{CCO}$  is the supply voltage associated with the output port.  $V_{CCA}$  must be less than or equal to  $V_{CCB}$ , and  $V_{CCA}$  must not exceed 3.6 V.

## 6.7 Timing Requirements: V<sub>CCA</sub> = 1.8 V ± 0.15 V

over recommended operating free-air temperature range,  $V_{CCA}$  = 1.8 V ± 0.15 V (unless otherwise noted)

|                |                 |                    | 3 7 00A     | ,   | MIN | MAX | UNIT  |
|----------------|-----------------|--------------------|-------------|---|-----|-----|-------|
|                | Data rate       | Push-pull driving  |             | $V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$<br>$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$<br>$V_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$ |     | 24  | Mbps  |
|                |                 | Open-drain driving |             | $V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$<br>$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$<br>$V_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$ |     | 2   | Wibps |
| t <sub>w</sub> | Pulse duration  | Push-pull driving  | Data inputs | $V_{CCB}$ = 2.5 V ± 0.2 V<br>$V_{CCB}$ = 3.3 V ± 0.3 V<br>$V_{CCB}$ = 5 V ± 0.5 V   | 41  |     | ns    |
| -W             | i disc duration | Open-drain driving | Data inputs | $V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$<br>$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$<br>$V_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$ | 500 |     | 113   |

## 6.8 Timing Requirements: $V_{CCA} = 2.5 V \pm 0.2 V$

over recommended operating free-air temperature range.  $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$  (unless otherwise noted)

|                |                |                    |             |   | MIN | MAX | UNIT |
|----------------|----------------|--------------------|-------------|---|-----|-----|------|
|                | Data rate      | Push-pull driving  |             | $V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $CCB = 3.3 \text{ V} \pm 0.3 \text{ V}$ $CCB = 5 \text{ V} \pm 0.5 \text{ V}$       |     | 24  | Mbps |
| Da             | Dala Tale      |                    |             | $V_{CCB} = 2.5 V \pm 0.2 V$ $_{CCB} = 3.3 V \pm 0.3 V$ $_{CCB} = 5 V \pm 0.5 V$   | 2   |     | Mbps |
| +              | - · · · ·      | Push-pull driving  | Data inputs | $V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$ | 41  |     | ns   |
| t <sub>w</sub> | Pulse duration | Open-drain driving | Data inputs | $V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$ | 500 |     | 115  |

## 6.9 Timing Requirements: $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$

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over recommended operating free-air temperature range, V<sub>CCA</sub> = 3.3 V ± 0.3 V (unless otherwise noted)

|                |                |                    |             |  | MIN | MAX | UNIT    |
|----------------|----------------|--------------------|-------------|--|-----|-----|---------|
|                | Data rate      |                    |             | V <sub>CCB</sub> = 3.3 V ± 0.3 V<br>V <sub>CCB</sub> = 5 V ± 0.5 V |     | 24  | Mbps    |
|                |                |                    |             | V <sub>CCB</sub> = 3.3 V ± 0.3 V<br>V <sub>CCB</sub> = 5 V ± 0.5 V | 2   |     | Reduivi |
|                | Dulas duration | Push-pull driving  | Data inputs | V <sub>CCB</sub> = 3.3 V ± 0.3 V<br>V <sub>CCB</sub> = 5 V ± 0.5 V | 41  |     | -       |
| t <sub>w</sub> | Pulse duration | Open-drain driving | Data inputs | V <sub>CCB</sub> = 3.3 V ± 0.3 V<br>V <sub>CCB</sub> = 5 V ± 0.5 V | 500 |     | ns      |



## 6.10 Switching Characteristics: $V_{CCA}$ = 1.8 V ± 0.15 V

over recommended operating free-air temperature range,  $V_{CCA}$  = 1.8 V  $\pm$  0.15 V (unless otherwise noted)

|     | PARAMETER   |              | TEST CON           | IDITIONS                                    | MIN | MAX  | UNIT |
|-----|---|--------------|--------------------|---|-----|------|------|
|     |   |              |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 4.6  |      |
|     |   |              | Push-pull driving  | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 4.7  |      |
|     | Propagation                                       |              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   |     | 5.8  |      |
| PHL | delay time<br>(high-to-low output)                |              |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 2.9 | 8.8  |      |
|     |   |              | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 2.9 | 9.6  |      |
|     |   | A 4 - D      |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 3   | 10   |      |
|     |   | A-to-B       |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 6.8  | ns   |
|     |   |              | Push-pull driving  | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 6.8  |      |
|     | Propagation                                       |              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   |     | 7    |      |
| PLH | delay time<br>(low-to-high output)                |              |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 45  | 260  |      |
|     | , ,   |              | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 36  | 208  |      |
|     |   |              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 27  | 198  |      |
|     |   |              |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 4.4  |      |
|     |   |              | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 4.5  |      |
|     | Propagation                                       |              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   |     | 4.7  |      |
| PHL | PHL delay time (high-to-low output)               |              |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 1.9 | 5.3  |      |
|     | ( )   |              | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 1.1 | 4.4  |      |
|     |   | D 45 A       |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 1.2 | 4    |      |
|     | Propagation<br>delay time<br>(low-to-high output) | B-to-A       | Push-pull driving  | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 5.3  | ns   |
|     |   |              |                    | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 4.5  |      |
|     |   |              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   |     | 0.5  |      |
| PLH |   |              | Open-drain driving | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 45  | 175  |      |
|     |   |              |                    | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 36  | 140  |      |
|     |   |              |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 27  | 102  |      |
|     |   | OE-to-A or B |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 200  |      |
| en  | Enable time                                       |              |                    | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 200  | ns   |
|     |   |              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   |     | 200  | -    |
|     |   |              |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 50   |      |
| dis | Disable time                                      | OE-to-A      | or B               | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 40   | ns   |
|     |   |              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   |     | 35   |      |
|     |   |              |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 3.2 | 9.5  |      |
|     |   |              | Push-pull driving  | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2.3 | 9.3  |      |
|     | land the size of the size                         | A-port       |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 2   | 7.6  | ]    |
| rA  | Input rise time                                   | rise time    |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 38  | 165  | ns   |
|     |   |              | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 30  | 132  |      |
|     |   |              |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 22  | 95   | 1    |
|     |   |              |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 4   | 10.8 |      |
|     |   |              | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 2.7 | 9.1  | 1    |
|     | Innut via a time -                                | B-port       |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 2.7 | 7.6  |      |
| rB  | Input rise time                                   | rise time    |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 34  | 145  | ns   |
|     |   |              | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 23  | 106  | 1    |
|     |   |              |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 10  | 58   | 1    |

## 6.10 Switching Characteristics: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (continued)

over recommended operating free-air temperature range, V<sub>CCA</sub> = 1.8 V ± 0.15 V (unless otherwise noted)

|       | PARAMETER             |                  | TEST CON           | IDITIONS                                    | MIN | MAX  | UNIT   |
|-------|-----------------------|------------------|--------------------|---|-----|------|--------|
|       |                       |                  |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 2   | 5.9  |        |
|       |                       |                  | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 1.9 | 6    |        |
| ١     | Input fall time       | A-port           |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 1.7 | 13.3 | ns     |
| fA    | input iali time       | fall time        |                    | $V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$ | 4.4 | 6.9  | 115    |
|       |                       |                  | Open-drain driving | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 4.3 | 6.4  |        |
|       |                       |                  |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 4.2 | 6.1  |        |
|       |                       |                  |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 2.9 | 7.6  |        |
|       |                       |                  | Push-pull driving  | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2.8 | 7.5  |        |
|       | Input fall time       | B-port fall time |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 2.8 | 8.8  | ns     |
| fB    |                       |                  | Open-drain driving | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 6.9 | 13.8 | 115    |
|       |                       |                  |                    | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 7.5 | 16.2 |        |
|       |                       |                  |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 7   | 16.2 |        |
|       |                       |                  |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 1    | ns     |
| SK(O) | Skew (time), output   | Channel-         | to-channel skew    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 1    |        |
|       |                       |                  |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 1    |        |
|       |                       |                  |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 24  |      |        |
|       |                       |                  | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 24  |      |        |
|       | Maximum data rate     |                  |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 24  |      | Mbps   |
|       | maxiiiluiii uata iate |                  |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 2   |      | IVIDPS |
|       |                       |                  | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 2   |      |        |
|       |                       |                  |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 2   |      |        |

## 6.11 Switching Characteristics: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range,  $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$  (unless otherwise noted)

|                  | PARAMETER   |        | TEST CON           | IDITIONS                                    | MIN | MAX | UNIT |
|------------------|---|--------|--------------------|---|-----|-----|------|
|                  |   |        |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 3.2 |      |
|                  |   |        | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 3.3 | ]    |
|                  | Propagation delay time                            | A-to-B |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 3.4 | ]    |
| t <sub>PHL</sub> | (high-to-low output)                              | A-10-B |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 1.7 | 6.3 |      |
|                  |   |        | Open-drain driving | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2   | 6   | ]    |
|                  |   |        |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 2.1 | 5.8 | ns   |
|                  |   |        |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 3.5 | 115  |
|                  | Propagation<br>delay time<br>(low-to-high output) |        | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 4.1 | ]    |
|                  |   | A-to-B |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 4.4 | 1    |
| t <sub>PLH</sub> |   |        | Open-drain driving | $V_{CCB} = 2.5 V \pm 0.2 V$                 | 43  | 250 | ]    |
|                  |   |        |                    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 36  | 206 |      |
|                  |   |        |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 27  | 190 |      |
|                  |   |        |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 3   |      |
|                  |   |        | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 3.6 | 1    |
|                  | Propagation delay time                            | B-to-A |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 4.3 |      |
| t <sub>PHL</sub> | (high-to-low output)                              | D-10-A |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 1.8 | 4.7 | ns   |
|                  | ,   |        | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 2.6 | 4.2 | 1    |
|                  |   |        |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 1.2 | 4   | ]    |

## 6.11 Switching Characteristics: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (continued)

over recommended operating free-air temperature range,  $V_{CCA}$  = 2.5 V  $\pm$  0.2 V (unless otherwise noted)

|       | PARAMETER                          |                     | TEST CON           | IDITIONS                                    | MIN | MAX  | UNIT |
|-------|------------------------------------|---------------------|--------------------|---|-----|------|------|
|       |                                    |                     |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 2.5  |      |
|       |                                    |                     | Push-pull driving  | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 1.6  |      |
|       | Propagation                        | D to A              |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 0.7  |      |
| PLH   | delay time<br>(low-to-high output) | B-to-A              | Open-drain driving | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 44  | 170  |      |
|       | , ,                                |                     |                    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 37  | 140  |      |
|       |                                    |                     |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 27  | 103  |      |
|       |                                    |                     | ı                  | $V_{CCB} = 2.5 V \pm 0.2 V$                 |     | 200  |      |
| en    | Enable time                        | OE-to-A             | or B               | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 200  | ns   |
|       |                                    |                     |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 200  |      |
|       |                                    |                     |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 50   |      |
| dis   | Disable time                       | OE-to-A             | or B               | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 40   | ns   |
|       |                                    |                     |                    | $V_{CCB} = 5 V \pm 0.5 V$                   |     | 35   |      |
|       |                                    |                     |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 2.8 | 7.4  |      |
|       |                                    |                     | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 2.6 | 6.6  |      |
|       | lumint sia a tima a                | A-port              |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 1.8 | 5.6  |      |
| rA    | A Input rise time                  | rise time           |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 34  | 149  | ns   |
|       |                                    |                     |                    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 28  | 121  |      |
|       |                                    |                     |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 24  | 89   |      |
|       |                                    |                     |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 3.2 | 8.3  |      |
|       |                                    |                     |                    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2.9 | 7.2  |      |
|       | In word of a catherine             | me B-port rise time |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 2.4 | 6.1  |      |
| rB    | Input rise time                    |                     |                    | $V_{CCB} = 2.5 V \pm 0.2 V$                 | 35  | 151  | ns   |
|       |                                    |                     |                    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 24  | 112  |      |
|       |                                    |                     |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 12  | 64   | 1    |
|       |                                    |                     |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 1.9 | 5.7  |      |
|       |                                    |                     | Push-pull driving  | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 1.9 | 5.5  |      |
|       | lancet fall times                  | A-port              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 1.8 | 5.3  |      |
| fΑ    | Input fall time                    | fall time           |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 4.4 | 6.9  | ns   |
|       |                                    |                     | Open-drain driving | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 4.3 | 6.2  |      |
|       |                                    |                     |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 4.2 | 5.8  |      |
|       |                                    |                     |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 2.2 | 7.8  |      |
|       |                                    |                     | Push-pull driving  | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2.4 | 6.7  |      |
|       |                                    | B-port              |                    | $V_{CCB} = 5 V \pm 0.5 V$                   | 2.6 | 6.6  | -    |
| В     | Input fall time                    | fall time           |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V            | 5.1 | 8.8  | ns   |
|       |                                    |                     | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 5.4 | 9.4  | 1    |
|       |                                    |                     |                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 5.4 | 10.4 | 1    |
|       |                                    |                     | I .                | V <sub>CCB</sub> = 2.5 V ± 0.2 V            |     | 1    |      |
| SK(O) | Skew (time), output                | Channel-            | to-channel skew    | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 1    | ns   |
| . ,   | (O) Onew (time), output            |                     |                    | $V_{CCB} = 5 V \pm 0.5 V$                   |     | 1    | 1    |



## 6.11 Switching Characteristics: V<sub>CCA</sub> = 2.5 V ± 0.2 V (continued)

over recommended operating free-air temperature range,  $V_{CCA}$  = 2.5 V ± 0.2 V (unless otherwise noted)

| PARAMETER         | TEST CON           | MIN                              | MAX | UNIT |      |
|-------------------|--------------------|----------------------------------|-----|------|------|
|                   |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V | 24  |      |      |
|                   | Push-pull driving  | V <sub>CCB</sub> = 3.3 V ± 0.3 V | 24  |      |      |
| Maximum data rate |                    | V <sub>CCB</sub> = 5 V ± 0.5 V   | 24  |      | Mhna |
| Maximum data rate |                    | V <sub>CCB</sub> = 2.5 V ± 0.2 V | 2   |      | Mbps |
|                   | Open-drain driving | V <sub>CCB</sub> = 3.3 V ± 0.3 V | 2   |      |      |
|                   |                    | V <sub>CCB</sub> = 5 V ± 0.5 V   | 2   |      |      |

## 6.12 Switching Characteristics: $V_{CCA}$ = 3.3 V ± 0.3 V

over recommended operating free-air temperature range, V<sub>CCA</sub> = 3.3 V ± 0.3 V (unless otherwise noted)

|     | PARAMETER  |           | TEST CON                             | DITIONS                                     | MIN | MAX | UNIT |
|-----|--|-----------|--------------------------------------|---|-----|-----|------|
|     |  |           | Decade meetly alwinder as            | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 2.4 |      |
|     | Propagation  |           | Push-pull driving                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 3.1 |      |
| PHL | delay time<br>(high-to-low output)                 |           |                                      | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 1.3 | 4.2 |      |
|     | ( )  | A 4- D    | Open-drain driving                   | V <sub>CCB</sub> = 5 V ± 0.5 V              | 1.4 | 4.6 |      |
|     |  | A-to-B    | Decade meetly distriction            | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 4.2 | ns   |
|     | Propagation  |           | Push-pull driving                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 4.4 |      |
| PLH | delay time<br>(low-to-high output)                 |           | Open drain driving                   | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 36  | 204 |      |
|     | , , ,  |           | Open-drain driving                   | V <sub>CCB</sub> = 5 V ± 0.5 V              | 28  | 165 |      |
|     |  |           | Duck hull driving                    | V <sub>CCB</sub> = 3.3 V ± 0.3 V            |     | 2.5 |      |
|     | Propagation  |           | Push-pull driving                    | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 3.3 |      |
| PHL | o <sub>HL</sub> delay time<br>(high-to-low output) |           |                                      | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 1   | 124 |      |
|     | ( )  | D to A    | Open-drain driving                   | V <sub>CCB</sub> = 5 V ± 0.5 V              | 1   | 97  | ]    |
|     |  | B-to-A    | Push-null driving                    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 2.5 | ns   |
|     | Propagation<br>delay time<br>(low-to-high output)  |           |                                      | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 2.6 |      |
| PLH |  |           | Open drain driving                   | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 3   | 139 |      |
|     |  |           | Open-drain driving                   | V <sub>CCB</sub> = 5 V ± 0.5 V              | 3   | 105 |      |
|     | Cuabla tima  | OF 45 A   | D                                    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 200 |      |
| en  | Enable time  | OE-to-A   | or B                                 | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 200 | ns   |
|     | Disable the  | 05 to A   | D                                    | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |     | 40  | nc   |
| dis | Disable time                                       | OE-to-A   | or B                                 | V <sub>CCB</sub> = 5 V ± 0.5 V              |     | 35  | ns   |
|     |  |           | Describe an all abolishes as         | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 2.3 | 5.6 |      |
|     | land the size of the size                          | A-port    | Push-pull driving                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 1.9 | 4.8 | 1    |
| rA  | Input rise time                                    | rise time | On an dualing debate on              | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 25  | 116 | ns   |
|     |  |           | Open-drain driving                   | V <sub>CCB</sub> = 5 V ± 0.5 V              | 19  | 85  |      |
|     |  |           | December and the first of the second | $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2.5 | 6.4 |      |
|     | land the size of the size                          | B-port    | Push-pull driving                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 2.1 | 7.4 | 1    |
| rB  | Input rise time                                    | rise time |                                      | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 26  | 116 | ns   |
|     |  |           | Open-drain driving                   | V <sub>CCB</sub> = 5 V ± 0.5 V              | 26  | 116 |      |
|     |  |           | Duck mult definite a                 | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 2   | 5.4 |      |
|     | land to the fact of the car                        | A-port    | Push-pull driving                    | V <sub>CCB</sub> = 5 V ± 0.5 V              | 1.9 | 5   | 1    |
| fΑ  | Inniit tali time                                   | fall time | Open drain driver                    | V <sub>CCB</sub> = 3.3 V ± 0.3 V            | 4.3 | 6.1 | ns   |
|     |  |           | Open-drain driving                   | V <sub>CCB</sub> = 5 V ± 0.5 V              | 4.2 | 5.7 | 1    |

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# 6.12 Switching Characteristics: $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (continued)

over recommended operating free-air temperature range, V<sub>CCA</sub> = 3.3 V ± 0.3 V (unless otherwise noted)

|                    | PARAMETER            |                         | TEST CONDITIONS        |                                  |     | MAX | UNIT   |
|--------------------|----------------------|-------------------------|------------------------|----------------------------------|-----|-----|--------|
|                    |                      |                         | Push-pull driving      | V <sub>CCB</sub> = 3.3 V ± 0.3 V | 2.3 | 7.4 |        |
|                    | Input fall time      | B-port                  | Push-pull driving      | V <sub>CCB</sub> = 5 V ± 0.5 V   | 2.4 | 7.6 |        |
| t <sub>fB</sub>    | input iaii time      | fall time               | Open-drain driving     | V <sub>CCB</sub> = 3.3 V ± 0.3 V | 5   | 7.6 | ns     |
|                    |                      |                         | Open-drain driving     | V <sub>CCB</sub> = 5 V ± 0.5 V   | 4.8 | 8.3 |        |
| +                  | Skew (time), output  | Channel-to-channel skew |                        | V <sub>CCB</sub> = 3.3 V ± 0.3 V |     | 1   | no.    |
| t <sub>SK(O)</sub> | Skew (tille), output |                         |                        | V <sub>CCB</sub> = 5 V ± 0.5 V   |     | 1   | - ns   |
|                    |                      |                         | Push-pull driving      | V <sub>CCB</sub> = 3.3 V ± 0.3 V | 24  |     |        |
|                    | Maximum data rate    |                         | Push-pull driving      | V <sub>CCB</sub> = 5 V ± 0.5 V   | 24  |     | Mbps   |
|                    | Maximum data rate    |                         | Out of the data to the | V <sub>CCB</sub> = 3.3 V ± 0.3 V | 2   |     | IVIDPS |
|                    |                      |                         | Open-drain driving     | V <sub>CCB</sub> = 5 V ± 0.5 V   | 2   |     |        |

## **6.13 Typical Characteristics**

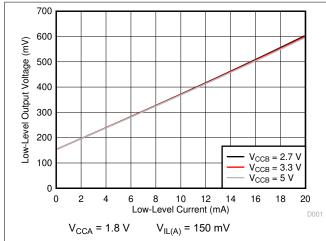


Figure 6-1. Low-Level Output Voltage (V<sub>OL(Ax)</sub>) vs Low-Level Current (I<sub>OL(Ax)</sub>)

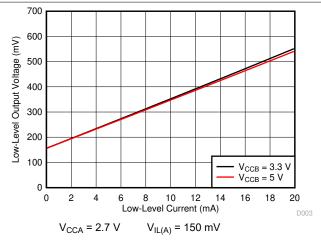


Figure 6-2. Low-Level Output Voltage (V<sub>OL(Ax)</sub>) vs Low-Level Current (I<sub>OL(Ax)</sub>)

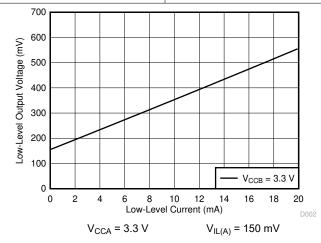


Figure 6-3. Low-Level Output Voltage  $(V_{OL(Ax)})$  vs Low-Level Current  $(I_{OL(Ax)})$ 



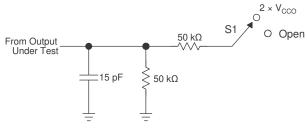
## 7 Parameter Measurement Information

## 7.1 Load Circuits



Figure 7-1. Data Rate, Pulse Duration, Propagation Delay, Output Rise-Time and Fall-Time Propagation Delay, Output Rise-Time and Fall-Time Measurement Using a Push-Pull Driver

Figure 7-2. Data Rate, Pulse Duration, Measurement Using an Open-Drain Driver



| TEST  | S1                   |
|---|----------------------|
| t <sub>PZL</sub> / t <sub>PLZ</sub> (t <sub>dis</sub> ) | 2 × V <sub>CCO</sub> |
| t <sub>PHZ</sub> / t <sub>PZH</sub> (t <sub>en</sub> )  | Open                 |

Figure 7-3. Load Circuit for Enable-Time and Disable-Time Measurement

- 1.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- 2.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- 3.  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
- 4.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.

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## 7.2 Voltage Waveforms

The outputs are measured one at a time, with one transition per measurement. All input pulses are supplied by generators that have the following characteristics:

- PRR ≤ 10 MHz
- $Z_{O} = 50 \Omega$
- dv/dt ≥ 1 V/ns

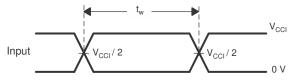


Figure 7-4. Pulse Duration

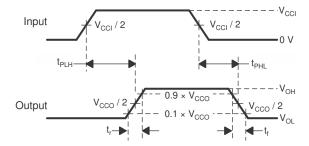
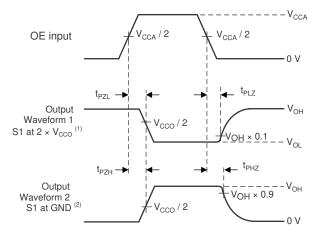


Figure 7-5. Propagation Delay Times



- A. Waveform 1 is for an output with internal such that the output is high, except when OE is high (see Figure 7-3).
- B. Waveform 2 is for an output with conditions such that the output is low, except when OE is high.

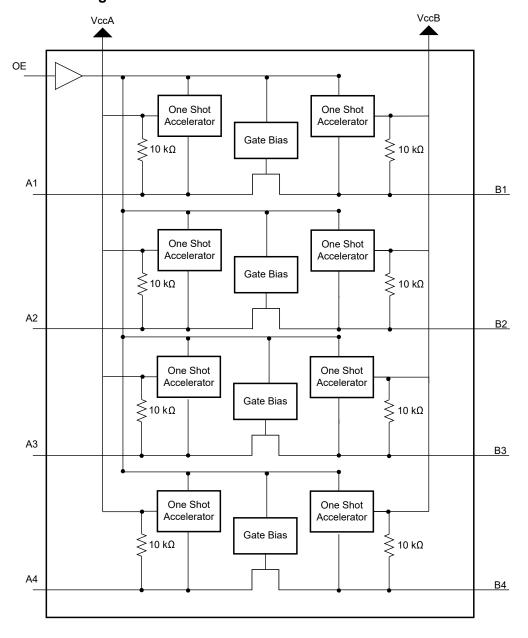
Figure 7-6. Enable and Disable Times

## **8 Detailed Description**

## 8.1 Overview

The TXS0104E device is a directionless voltage-level translator specifically designed for translating logic voltage levels. The A port is able to accept I/O voltages ranging from 1.65 V to 3.6 V, while the B port can accept I/O voltages from 2.3 V to 5.5 V. The device is a pass gate architecture with edge rate accelerators (one shots) to improve the overall data rate. 10-k $\Omega$  pullup resistors, commonly used in open drain applications, have been conveniently integrated so that an external resistor is not needed. While this device is designed for open drain applications, the device can also translate push-pull CMOS logic outputs.

### 8.2 Functional Block Diagram



#### 8.3 Feature Description

## 8.3.1 Architecture

The TXS0104E architecture (see Figure 8-1) does not require a direction-control signal in order to control the direction of data flow from A to B or from B to A.

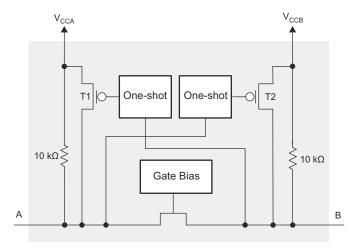


Figure 8-1. Architecture of a TXS01xx Cell

Each A-port I/O has an internal  $10-k\Omega$  pullup resistor to  $V_{CCA}$ , and each B-port I/O has an internal  $10-k\Omega$  pullup resistor to V<sub>CCB</sub>. The output one-shots detect rising edges on the A or B ports. During a rising edge, the one-shot turns on the PMOS transistors (T1, T2) for a short duration which speeds up the low-to-high transition.

#### 8.3.2 Input Driver Requirements

The fall time (t<sub>fA</sub>, t<sub>fB</sub>) of a signal depends on the output impedance of the external device driving the data I/Os of the TXS0104E device. Similarly, the t<sub>PHL</sub> and maximum data rates also depend on the output impedance of the external driver. The values for tfA, tfB, tPHL, and maximum data rates in the data sheet assume that the output impedance of the external driver is less than 50  $\Omega$ .

#### 8.3.3 Power Up

During operation, ensure that  $V_{CCA} \le V_{CCB}$  at all times. During power-up sequencing,  $V_{CCA} \ge V_{CCB}$  does not damage the device, so any power supply can be ramped up first.

#### 8.3.4 Enable and Disable

The TXS0104E device has an OE input that disables the device by setting OE low, which places all I/Os in the high-impedance state. The disable time (t<sub>dis</sub>) indicates the delay between the time when the OE pin goes low and when the outputs actually enter the high-impedance state. The enable time (ten) indicates the amount of time the user must allow for the one-shot circuitry to become operational after the OE pin is taken high.

#### 8.3.5 Pullup and Pulldown Resistors on I/O Lines

Each A-port I/O has an internal 10-k $\Omega$  pullup resistor to  $V_{CCA}$ , and each B-port I/O has an internal 10-k $\Omega$  pullup resistor to V<sub>CCB</sub>. If a smaller value of pullup resistor is required, an external resistor must be added from the I/O to  $V_{CCA}$  or  $V_{CCB}$  (in parallel with the internal 10-k $\Omega$  resistors).

#### 8.4 Device Functional Modes

The TXS0104E device has two functional modes, enabled and disabled. To disable the device set the OE input low, which places all I/Os in a high impedance state. Setting the OE input high will enable the device.

## 9 Application and Implementation

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 9.1 Application Information

The TXS0104E device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The TXS0104E device is an excellent choice for applications where an open-drain driver is connected to the data I/Os. The TXS0104E device can also be used in applications where a push-pull driver is connected to the data I/Os, but the TXB0104 device might be a better option for such push-pull applications.

### 9.2 Typical Application

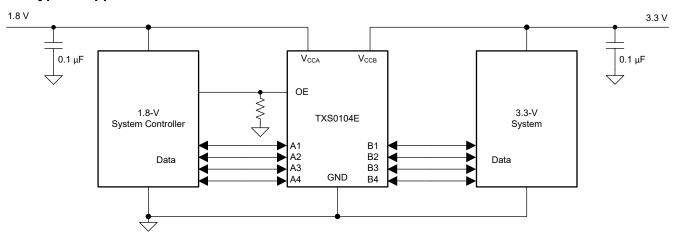


Figure 9-1. Application Schematic

#### 9.2.1 Design Requirements

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For this design example, use the parameters listed in Table 9-1.

**Table 9-1. Design Parameters** 

| DESIGN PARAMETER     | EXAMPLE VALUE |
|----------------------|---------------|
| Input voltage range  | 1.65 to 3.6 V |
| Output voltage range | 2.3 to 5.5 V  |

### 9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- · Input voltage range
  - Use the supply voltage of the device that is driving the TXS0104E device to determine the input voltage range. For a valid logic high the value must exceed the V<sub>IH</sub> of the input port. For a valid logic low the value must be less than the V<sub>IL</sub> of the input port.
- · Output voltage range
  - Use the supply voltage of the device that the TXS0104E device is driving to determine the output voltage range.
  - The TXS0104E device has 10-kΩ internal pullup resistors. External pullup resistors can be added to reduce the total RC of a signal trace if necessary.
- An external pull down resistor decreases the output V<sub>OH</sub> and V<sub>OL</sub>. Use Equation 1 to calculate the V<sub>OH</sub> as a
  result of an external pull down resistor.

$$V_{OH} = V_{CCx} \times R_{PD} / (R_{PD} + 10 \,k\Omega) \tag{1}$$

where

 $V_{CCx}$  is the supply voltage on either  $V_{CCA}$  or  $V_{CCB}$   $R_{PD}$  is the value of the external pull down resistor

### 9.2.3 Application Curve

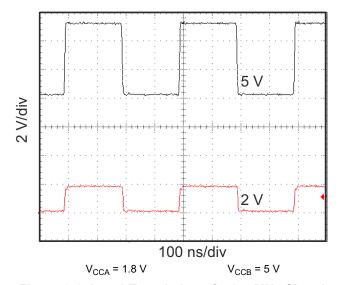


Figure 9-2. Level-Translation of a 2.5-MHz Signal

### 9.3 Power Supply Recommendations

The TXS0104E device uses two separate configurable power-supply rails,  $V_{CCA}$  and  $V_{CCB}$ .  $V_{CCB}$  accepts any supply voltage from 2.3 V to 5.5 V and  $V_{CCA}$  accepts any supply voltage from 1.65 V to 3.6 V as long as Vs is less than or equal to  $V_{CCB}$ . The A port and B port are designed to track  $V_{CCA}$  and  $V_{CCB}$  respectively allowing for low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

The TXS0104E device does not require power sequencing between  $V_{CCA}$  and  $V_{CCB}$  during power-up so the power-supply rails can be ramped in any order. A  $V_{CCA}$  value greater than or equal to  $V_{CCB}$  ( $V_{CCA} \ge V_{CCB}$ ) does not damage the device, but during operation,  $V_{CCA}$  must be less than or equal to  $V_{CCB}$  ( $V_{CCA} \le V_{CCB}$ ) at all times.

The output-enable (OE) input circuit is designed so that it is supplied by  $V_{CCA}$  and when the (OE) input is low, all outputs are placed in the high-impedance state. For the high-impedance state of the outputs during power up or power down, the OE input pin must be tied to GND through a pulldown resistor and must not be enabled until  $V_{CCA}$  and  $V_{CCB}$  are fully ramped and stable. The minimum value of the pulldown resistor to ground is determined by the current-sourcing capability of the driver.

### 9.4 Layout

### 9.4.1 Layout Guidelines

For device reliability, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading.
- PCB signal trace-lengths must be kept short enough so that the round-trip delay of any reflection is less than the one shot duration, approximately 30 ns, and encounters low impedance at the source driver.
- Placing pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals depending on the system requirements

#### 9.4.2 Layout Example

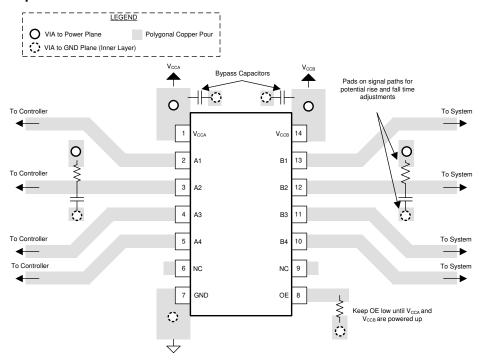


Figure 9-3. TXS0104E Layout Example



## 10 Device and Documentation Support

## **10.1 Documentation Support**

#### 10.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, Effects of External Pullup and Pulldown Resistors on TXS and TXB Devices application report
- Texas Instruments, Basics of Voltage Translation application report
- Texas Instruments, A Guide to Voltage Translation With TXS-Type Translators application report

### 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 10.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### 10.4 Trademarks

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## 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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## **PACKAGING INFORMATION**

| Orderable part number | Status (1) | Material type | Package   Pins   | Package qty   Carrier | <b>RoHS</b> (3) | Lead finish/<br>Ball material | MSL rating/<br>Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|------------------|-----------------------|-----------------|-------------------------------|----------------------------|--------------|------------------|
| TXS0104EBQAR          | Active     | Production    | WQFN (BQA)   14  | 3000   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | YF04E            |
| TXS0104EBQAR.A        | Active     | Production    | WQFN (BQA)   14  | 3000   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | YF04E            |
| TXS0104ED             | Active     | Production    | SOIC (D)   14    | 50   TUBE             | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | TXS0104E         |
| TXS0104ED.B           | Active     | Production    | SOIC (D)   14    | 50   TUBE             | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | TXS0104E         |
| TXS0104EDG4           | Active     | Production    | SOIC (D)   14    | 50   TUBE             | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | TXS0104E         |
| TXS0104EDR            | Active     | Production    | SOIC (D)   14    | 2500   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | TXS0104E         |
| TXS0104EDR.A          | Active     | Production    | SOIC (D)   14    | 2500   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | TXS0104E         |
| TXS0104EDR.B          | Active     | Production    | SOIC (D)   14    | 2500   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | TXS0104E         |
| TXS0104EDRG4          | Active     | Production    | SOIC (D)   14    | 2500   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | TXS0104E         |
| TXS0104EDRG4.A        | Active     | Production    | SOIC (D)   14    | 2500   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | TXS0104E         |
| TXS0104EDRG4.B        | Active     | Production    | SOIC (D)   14    | 2500   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | TXS0104E         |
| TXS0104ENMNR          | Active     | Production    | NFBGA (NMN)   12 | 2500   LARGE T&R      | Yes             | SNAGCU                        | Level-2-260C-1 YEAR        | -40 to 85    | 29XW             |
| TXS0104ENMNR.B        | Active     | Production    | NFBGA (NMN)   12 | 2500   LARGE T&R      | Yes             | SNAGCU                        | Level-2-260C-1 YEAR        | -40 to 85    | 29XW             |
| TXS0104EPWR           | Active     | Production    | TSSOP (PW)   14  | 2000   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | YF04E            |
| TXS0104EPWR.A         | Active     | Production    | TSSOP (PW)   14  | 2000   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | YF04E            |
| TXS0104EPWR.B         | Active     | Production    | TSSOP (PW)   14  | 2000   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | YF04E            |
| TXS0104EPWRG4         | Active     | Production    | TSSOP (PW)   14  | 2000   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | YF04E            |
| TXS0104ERGYR          | Active     | Production    | VQFN (RGY)   14  | 3000   LARGE T&R      | Yes             | NIPDAU                        | Level-2-260C-1 YEAR        | -40 to 85    | YF04E            |
| TXS0104ERGYR.A        | Active     | Production    | VQFN (RGY)   14  | 3000   LARGE T&R      | Yes             | NIPDAU                        | Level-2-260C-1 YEAR        | -40 to 85    | YF04E            |
| TXS0104ERGYR.B        | Active     | Production    | VQFN (RGY)   14  | 3000   LARGE T&R      | Yes             | NIPDAU                        | Level-2-260C-1 YEAR        | -40 to 85    | YF04E            |
| TXS0104ERGYRG4        | Active     | Production    | VQFN (RGY)   14  | 3000   LARGE T&R      | Yes             | NIPDAU                        | Level-2-260C-1 YEAR        | -40 to 85    | YF04E            |
| TXS0104ERUTR          | Active     | Production    | UQFN (RUT)   12  | 3000   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | 1RP              |
| TXS0104ERUTR.A        | Active     | Production    | UQFN (RUT)   12  | 3000   LARGE T&R      | Yes             | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | 1RP              |
| TXS0104EYZTR          | Active     | Production    | DSBGA (YZT)   12 | 3000   LARGE T&R      | Yes             | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 85    | 2N               |
| TXS0104EYZTR.B        | Active     | Production    | DSBGA (YZT)   12 | 3000   LARGE T&R      | Yes             | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 85    | 2N               |

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

## PACKAGE OPTION ADDENDUM

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(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF TXS0104E:

Automotive: TXS0104E-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



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## TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device       | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|--------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TXS0104EBQAR | WQFN            | BQA                | 14 | 3000 | 180.0                    | 12.4                     | 2.8        | 3.3        | 1.1        | 4.0        | 12.0      | Q1               |
| TXS0104EDR   | SOIC            | D                  | 14 | 2500 | 330.0                    | 12.4                     | 3.75       | 3.75       | 1.15       | 8.0        | 12.0      | Q1               |
| TXS0104EDRG4 | SOIC            | D                  | 14 | 2500 | 330.0                    | 12.4                     | 3.75       | 3.75       | 1.15       | 8.0        | 12.0      | Q1               |
| TXS0104ENMNR | NFBGA           | NMN                | 12 | 2500 | 180.0                    | 8.4                      | 2.3        | 2.8        | 1.15       | 4.0        | 8.0       | Q2               |
| TXS0104EPWR  | TSSOP           | PW                 | 14 | 2000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |
| TXS0104ERGYR | VQFN            | RGY                | 14 | 3000 | 330.0                    | 12.4                     | 3.75       | 3.75       | 1.15       | 8.0        | 12.0      | Q1               |
| TXS0104ERGYR | VQFN            | RGY                | 14 | 3000 | 330.0                    | 12.4                     | 3.75       | 3.75       | 1.15       | 8.0        | 12.0      | Q1               |
| TXS0104ERUTR | UQFN            | RUT                | 12 | 3000 | 180.0                    | 8.4                      | 2.0        | 2.3        | 0.75       | 4.0        | 8.0       | Q1               |
| TXS0104EYZTR | DSBGA           | YZT                | 12 | 3000 | 180.0                    | 8.4                      | 1.49       | 1.99       | 0.75       | 4.0        | 8.0       | Q2               |



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\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TXS0104EBQAR | WQFN         | BQA             | 14   | 3000 | 210.0       | 185.0      | 35.0        |
| TXS0104EDR   | SOIC         | D               | 14   | 2500 | 353.0       | 353.0      | 32.0        |
| TXS0104EDRG4 | SOIC         | D               | 14   | 2500 | 353.0       | 353.0      | 32.0        |
| TXS0104ENMNR | NFBGA        | NMN             | 12   | 2500 | 210.0       | 185.0      | 35.0        |
| TXS0104EPWR  | TSSOP        | PW              | 14   | 2000 | 353.0       | 353.0      | 32.0        |
| TXS0104ERGYR | VQFN         | RGY             | 14   | 3000 | 353.0       | 353.0      | 32.0        |
| TXS0104ERGYR | VQFN         | RGY             | 14   | 3000 | 360.0       | 360.0      | 36.0        |
| TXS0104ERUTR | UQFN         | RUT             | 12   | 3000 | 210.0       | 185.0      | 35.0        |
| TXS0104EYZTR | DSBGA        | YZT             | 12   | 3000 | 182.0       | 182.0      | 20.0        |

## **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



#### \*All dimensions are nominal

| Device      | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| TXS0104ED   | D            | SOIC         | 14   | 50  | 506.6  | 8      | 3940   | 4.32   |
| TXS0104ED.B | D            | SOIC         | 14   | 50  | 506.6  | 8      | 3940   | 4.32   |
| TXS0104EDG4 | D            | SOIC         | 14   | 50  | 506.6  | 8      | 3940   | 4.32   |

3.5 x 3.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
   The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK - NO LEAD



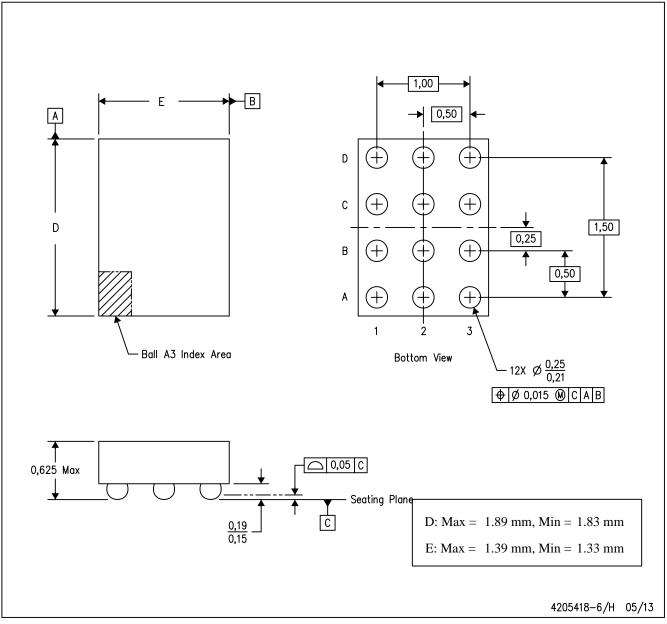
NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



YZT (R-XBGA-N12)

(CUSTOM) DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.





SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

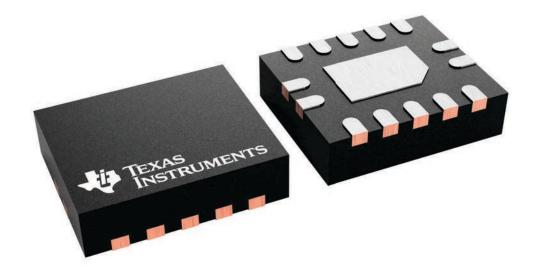
- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



PLASTIC QUAD FLAT PACK-NO LEAD



## NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLAT PACK-NO LEAD

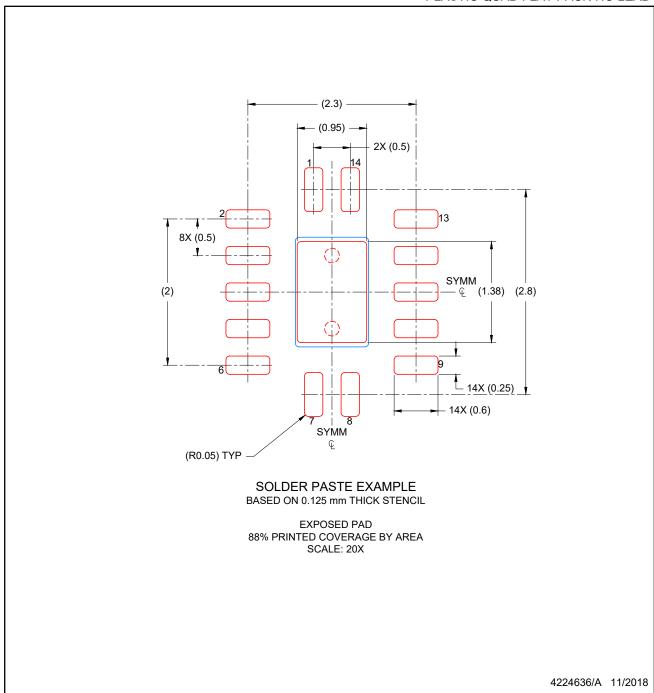


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLAT PACK-NO LEAD



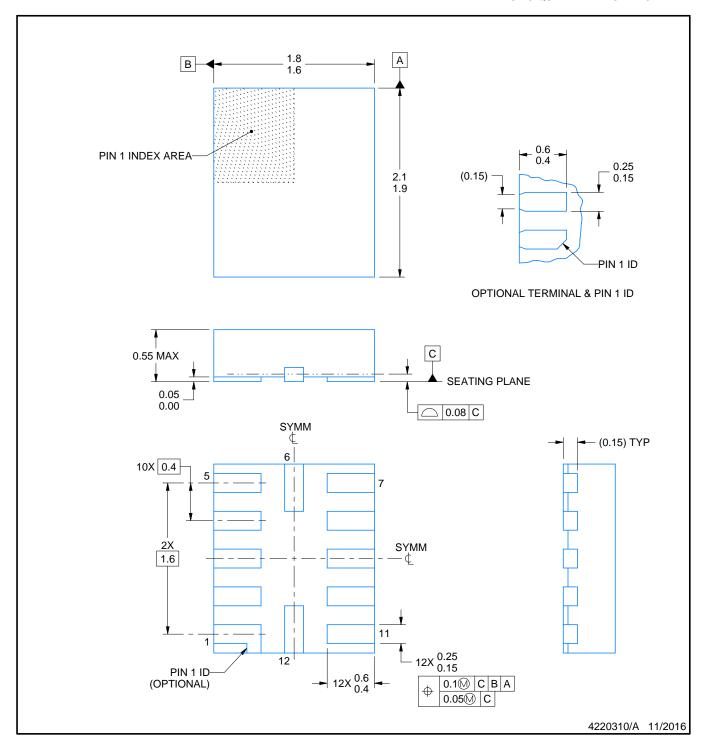
NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





PLASTIC QUAD FLATPACK - NO LEAD

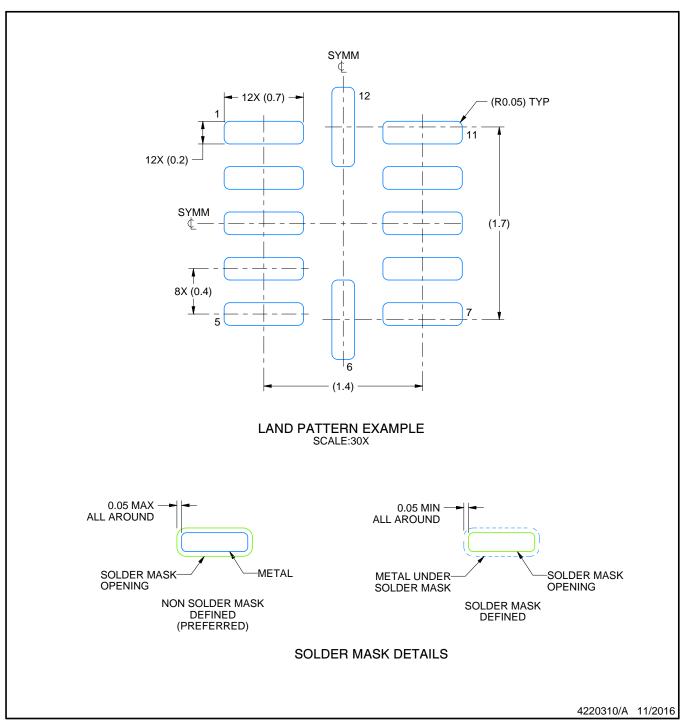


## NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.



PLASTIC QUAD FLATPACK - NO LEAD

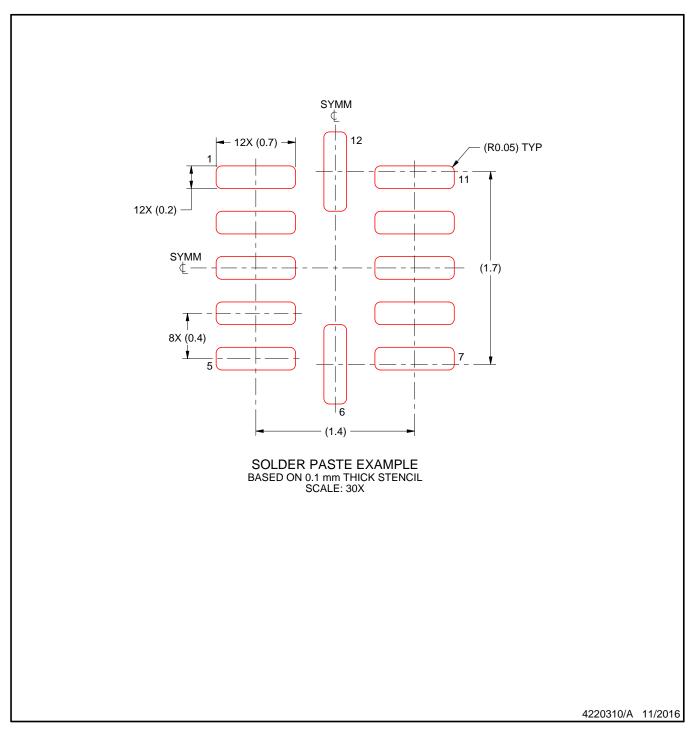


NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK - NO LEAD

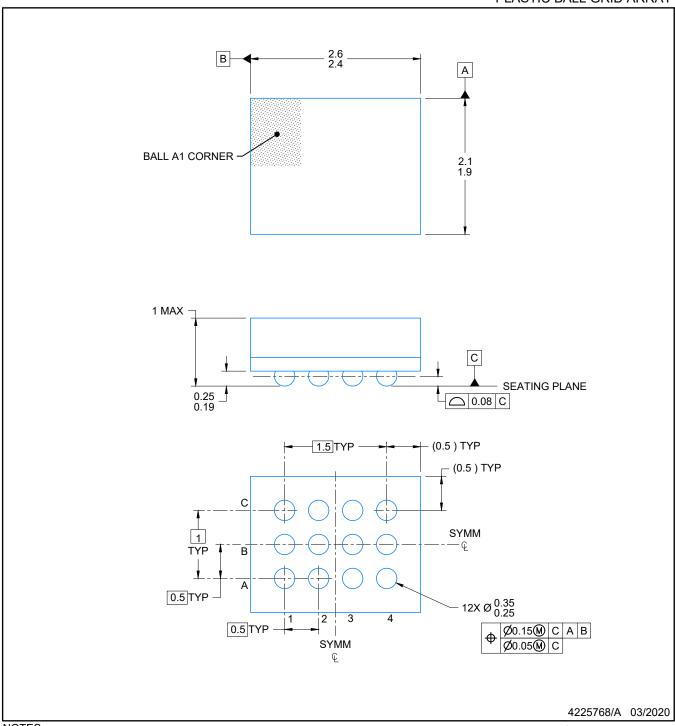


NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PLASTIC BALL GRID ARRAY



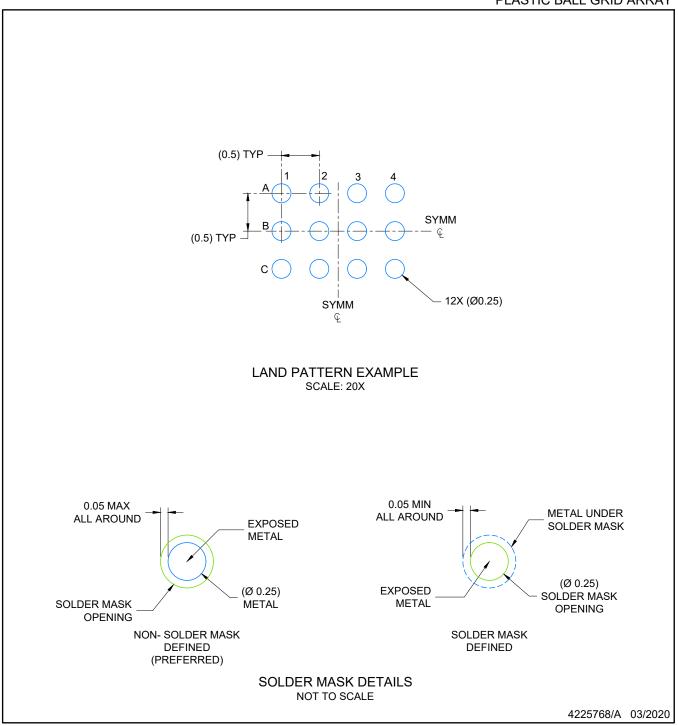
NOTES:

NanoFree is a trademark of Texas Instruments.

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



PLASTIC BALL GRID ARRAY

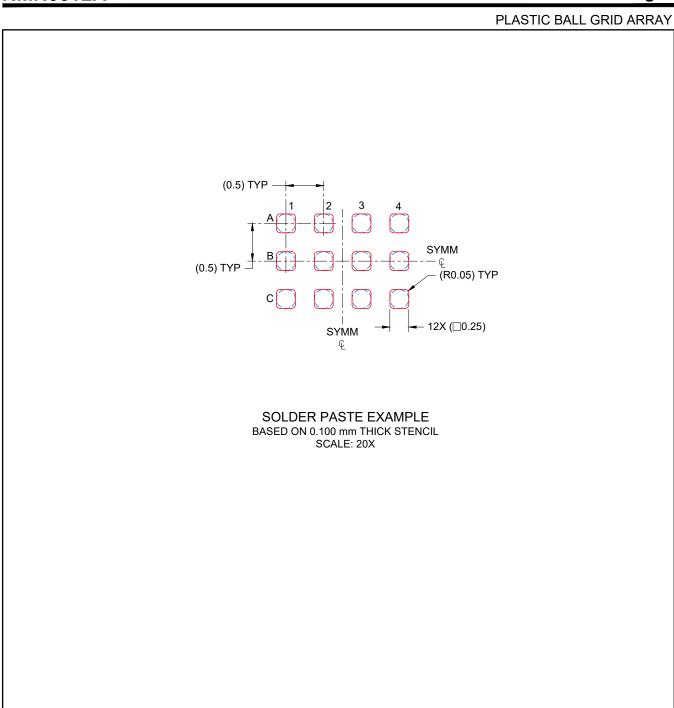


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. Refer to Texas Instruments Literature number SNVA009 (www.ti.com/lit/snva009).



4225768/A 03/2020



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



SMALL OUTLINE PACKAGE



## NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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